VALUE



# 600W, 5V - 170V Surface Mount Transient Voltage Suppressor

#### **FEATURES**

- · Ideal for automated placement
- · Glass passivated junction
- Excellent clamping capability
- Fast response time: Typically less than 1.0ps
- Typical I<sub>R</sub> less than 1µA above 10V
- Moisture sensitivity level: level 1, per J-STD-020
- AEC-Q101 qualified available: ordering code with suffix "H"
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC

$V_{WM}$	5 - 170	V	
V <sub>BR</sub> (uni - directional)	6.4 – 231	>	
V <sub>BR</sub> (bi - directional)	6.4 – 231	V	
P <sub>PK</sub>	600	W	
T <sub>J MAX</sub>	150	°C	
Package	DO-214AA	(SMB)	
Configuration	Single Die		

**KEY PARAMETERS** 

PARAMETER

# Pb ROHS

# **APPLICATIONS**

Switching mode power supply (SMPS)

#### **MECHANICAL DATA**

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.09 g (approximately)



DO-214AA (SMB)

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Non-repetitive peak impulse power dissipation with 10/1000µs waveform <sup>(1)</sup>	P <sub>PK</sub>	600	W			
Steady state power dissipation at T <sub>A</sub> =25°C	$P_{D}$	3	W			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load for Uni-directional only	I <sub>FSM</sub>	100	А			
Forward Voltage @ I <sub>F</sub> =50A for Uni-directional only (2)	$V_{F}$	3.5 / 5.0	V			
Junction temperature	T <sub>J</sub>	- 55 to +150	°C			
Storage temperature	T <sub>STG</sub>	- 55 to +150	°C			

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#### Notes:

- 1. Non-repetitive current pulse per Fig. 3 and derated above  $T_A$ =25°C per Fig. 2
- 2.  $V_F$ =3.5V on SMBJ5.0 SMBJ90 devices and  $V_F$ =5.0V on SMBJ100 SMBJ170 devices

#### **Devices for Bipolar Applications**

- 1. For bidirectional use C or CA suffix for types SMBJ5.0 types SMBJ170
- 2. Electrical characteristics apply in both directions



# Taiwan Semiconductor

THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP	UNIT			
Junction-to-Case Thermal Resistance	R <sub>eJC</sub>	10	°C/W			
Junction-to-Ambient Thermal Resistance	$R_{\Theta JA}$	55	°C/W			

			NS (T <sub>A</sub> =				Maximum	
Part number	Marking code	Breakdown voltage V <sub>BR</sub> @I <sub>T</sub> (V) (Note 1)		Test current I <sub>T</sub> (mA)	Working stand-off voltage V <sub>WM</sub> (V)	Maximum blocking leakage current l <sub>D</sub> @V <sub>WM</sub> (μA)	peak impulse current I <sub>PP</sub> (A)	Maximum clamping voltage Vc@l <sub>PP</sub> (V)
		Min.	Max.				(Note 2)	
SMBJ5.0	KD	6.40	7.30	10	5.0	800	65.0	9.6
SMBJ5.0A	KE	6.40	7.00	10	5.0	800	68.0	9.2
SMBJ6.0	KF	6.67	8.15	10	6.0	800	55.0	11.4
SMBJ6.0A	KG	6.67	7.37	10	6.0	800	61.0	10.3
SMBJ6.5	KH	7.22	8.82	10	6.5	500	51.0	12.3
SMBJ6.5A	KK	7.22	7.98	10	6.5	500	56.0	11.2
SMBJ7.0	KL	7.78	9.51	10	7.0	200	47.0	13.3
SMBJ7.0A	KM	7.78	8.60	10	7.0	200	52.0	12.0
SMBJ7.5	KN	8.33	10.3	1	7.5	100	44.0	14.3
SMBJ7.5A	KP	8.33	9.21	1	7.5	100	48.0	12.9
SMBJ8.0	KQ	8.89	10.9	1	8.0	50	42.0	15.0
SMBJ8.0A	KR	8.89	9.83	1	8.0	50	46.0	13.6
SMBJ8.5	KS	9.44	11.5	1	8.5	10	39.0	15.9
SMBJ8.5A	KT	9.44	10.4	1	8.5	10	43.0	14.4
SMBJ9.0	KU	10.0	12.2	1	9.0	5	37.0	16.9
SMBJ9.0A	KV	10.0	11.1	1	9.0	5	40.0	15.4
SMBJ10	KW	11.1	13.6	1	10	5	33.0	18.8
SMBJ10A	KX	11.1	12.3	1	10	5	37.0	17.0
SMBJ11	KY	12.2	14.9	1	11	1	31.0	20.1
SMBJ11A	KZ	12.2	13.5	1	11	1	34.0	18.2
SMBJ12	LD	13.3	16.3	1	12	1	28.0	22.0
SMBJ12A	LE	13.3	14.7	1	12	1	31.0	19.9
SMBJ13	LF	14.4	17.6	1	13	1	26.0	23.8
SMBJ13A	LG	14.4	15.9	1	13	1	29.0	21.5
SMBJ14	LH	15.6	19.1	1	14	1	24.4	25.8
SMBJ14A	LK	15.6	17.2	1	14	1	27.0	23.2
SMBJ15	LL	16.7	20.4	1	15	1	23.1	26.9
SMBJ15A	LM	16.7	18.5	1	15	1	25.1	24.4
SMBJ16	LN	17.8	21.8	1	16	1	21.8	28.8
SMBJ16A	LP	17.8	19.7	1	16	1	24.2	26.0
SMBJ17	LQ	18.9	23.1	1	17	1	20.0	30.5
SMBJ17A	LR	18.9	20.9	1	17	1	22.8	27.6
SMBJ18	LS	20.0	24.4	1	18	1	19.5	32.2
SMBJ18A	LT	20.0	22.1	1	18	1	21.5	29.2
SMBJ20	LU	22.2	27.1	1	20	1	17.6	35.8
SMBJ20A	LV	22.2	24.5	1	20	1	19.4	32.4
SMBJ22	LW	24.4	29.8	1	22	1	15.0	39.4
SMBJ22A	LX	24.4	26.9	1	22	1	17.7	35.5
SMBJ24	LY	26.7	32.6	1	24	1	14.6	43.0
SMBJ24A	LZ	26.7	29.5	1	24	1	16.0	38.9
SMBJ26	MD	28.9	35.3	1	26	1	13.5	46.6
SMBJ26A	ME	28.9	31.9	1 1	26	1	14.9	42.1



# SMBJ SERIES Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)								
	Marking code	Breakdow V <sub>BR</sub> (\ (Not	vn voltage <b>@l</b> ⊤ /) te 1)	Test current I <sub>T</sub> (mA)	Working stand-off voltage V <sub>WM</sub> (V)	Maximum blocking leakage current I <sub>D</sub> @V <sub>WM</sub> (μA)	Maximum peak impulse current I <sub>PP</sub> (A)	Maximum clamping voltage V <sub>C</sub> @l <sub>PP</sub> (V)
		Min.	Max.			(	(Note 2)	
SMBJ28	MF	31.1	38.0	1	28	1	12.6	50.0
SMBJ28A	MG	31.1	34.4	1	28	1	13.8	45.4
SMBJ30	MH	33.3	40.7	1	30	1	11.7	53.5
SMBJ30A	MK	33.3	36.8	1	30	1	13.0	48.4
SMBJ33	ML	36.7	44.9	1	33	1	10.6	59.0
SMBJ33A	MM	36.7	40.6	1	33	1	11.8	53.3
SMBJ36	MN	40.0	48.9	1	36	1	9.8	64.3
SMBJ36A	MP	40.0	44.2	1	36	1	10.8	58.1
SMBJ40	MQ	44.4	54.3	1	40	1	8.8	71.4
SMBJ40A	MR	44.4	49.1	1	40	1	9.7	64.5
SMBJ43	MS	47.8	58.4	1	43	1	8.2	76.7
SMBJ43A	MT	47.8	52.8	1	43	1	9.0	69.4
SMBJ45	MU	50.0	61.1	1	45	1	7.8	80.3
SMBJ45A	MV	50.0	55.3	1	45	1	8.6	72.7
SMBJ48	MW	53.3	65.1	1	48	1	7.3	85.5
SMBJ48A	MX	53.3	58.9	1	48	1	8.1	77.4
SMBJ51	MY	56.7	69.3	1	51	1	6.9	91.1
SMBJ51A	MZ	56.7	62.7	1	51	1	7.6	82.4
SMBJ54	ND	60.0	73.3	1	54	1	6.5	96.3
SMBJ54A	NE	60.0	66.3	1	54	1	7.2	87.1
SMBJ58	NF	64.4	78.7	1	58	1	6.1	103
SMBJ58A	NG	64.4	71.2	1	58	1	6.7	93.6
SMBJ60	NH	66.7	81.5	1	60	1	5.8	107
SMBJ60A	NK	66.7	73.7	1	60	1	6.5	96.8
SMBJ64	NL NL	71.1	86.9	1	64	1	5.5	114
SMBJ64A	NM	71.1	78.6	1	64	1	6.1	103
SMBJ70	NN	77.8	95.1	1	70	1	5.0	125
SMBJ70A	NP	77.8	86	1	70	1	5.5	113
SMBJ75	NQ	83.3	102		75		4.7	134
SMBJ75A	NR NR	83.3	92.1	<u> </u>	75	1 1	5.2	121
SMBJ78	NS NS	86.7	106	1	78	1	4.5	139
SMBJ78A	NT	86.7	95.8	1	78	1	5.0	126
SMBJ85	NU	94.4	115	1	85	1	4.1	151
SMBJ85A	NV	94.4	104	1	85	1	4.1	137
	NW		104	1	90	1		
SMBJ90		100					3.9	160
SMBJ90A	NX	100	111	1	90	1	4.3	146
SMBJ100	NY	111	136	1	100	1	3.5	179
SMBJ100A	NZ DD	111	123	1	100	1	3.8	162
SMBJ110	PD	122	149	1	110	1	3.2	196
SMBJ110A	PE	122	135	1	110	1	3.5	177
SMBJ120	PF	133	163	1	120	1	2.9	214
SMBJ120A	PG	133	147	1	120	1	3.2	193
SMBJ130	PH	144	176	1	130	1	2.7	231
SMBJ130A	PK	144	159	1	130	1	3.0	209
SMBJ150	PL	167	204	1	150	1	2.3	266
SMBJ150A	PM	167	185	1	150	1	2.5	243
SMBJ160	PN	178	218	1	160	1	2.2	287
SMBJ160A	PP	178	197	1	160	1	2.4	259
SMBJ170	PQ	189	231	1	170	1	2.0	304



# Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T <sub>A</sub> = 25°C unless otherwise noted)								
Part number	Marking code	Breakdown voltage V <sub>BR</sub> @I <sub>T</sub> (V) (Note 1)		Test current I <sub>T</sub> (mA)	Working stand-off voltage V <sub>WM</sub> (V)	Maximum blocking leakage current I <sub>D</sub> @V <sub>WM</sub> (μA)	Maximum peak impulse current I <sub>PP</sub> (A)	Maximum clamping voltage V <sub>C</sub> @I <sub>PP</sub> (V)
		Min.	Max.			(P/ 1)	(Note 2)	
SMBJ170A	PR	189	209	1	170	1	2.2	275

#### Notes:

- 1.  $V_{BR}$  measure after  $I_T$  applied for 30ms,  $I_T$ =square wave pulse or equivalent.
- 2. Surge current waveform per Figure. 3 and derate per Figure. 2.
- 3. All terms and symbols are consistent with ANSI/IEEE C62.35.
- 4. For bidirectional use C or CA suffix for types SMBJ5.0 SMBJ170
- 5. For bipolar types having  $V_{WM}$  of 10 V (SMBJ8.0C) and under, the  $I_D$  limit is doubled.

RDERING INFORMATION					
ORDERING CODE (Note 1,2,3)	PACKAGE	PACKING			
SMBJxxxxHR5G	SMB	850 / 7" Plastic reel			
SMBJxxxxHR4G	SMB	3,000 / 13" Paper reel			
SMBJxxxxHM4G	SMB	3,000 / 13" Plastic reel			
SMBJxxxx R5G	SMB	850 / 7" Plastic reel			
SMBJxxxx R4G	SMB	3,000 / 13" Paper reel			
SMBJxxxx M4G	SMB	3,000 / 13" Plastic reel			
SMBJxxxxHR5	SMB	850 / 7" Plastic reel			
SMBJxxxxHR4	SMB	3,000 / 13" Paper reel			
SMBJxxxxHM4	SMB	3,000 / 13" Plastic reel			
SMBJxxxx R5	SMB	850 / 7" Plastic reel			
SMBJxxxx R4	SMB	3,000 / 13" Paper reel			
SMBJxxxx M4	SMB	3,000 / 13" Plastic reel			

### Note 1:

"xxxx" defines voltage from 5.0V (SMBJ5.0) to 170V (SMBJ170A)

#### Note 2:

"H" means AEC-Q101 qualified

#### Note 3:

"G" means green compound (halogen free)





### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig1. Peak Pulse Power rating Curve

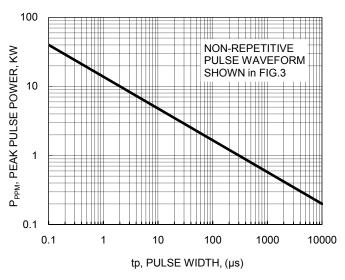


Fig2. Pulse Derating Curve

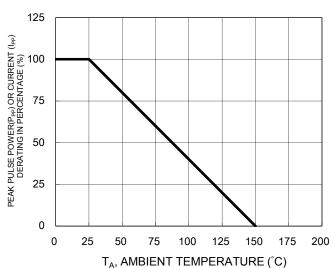


Fig3. Clamping Power Pulse Waveform

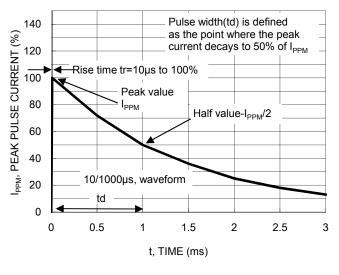


Fig4. Maximum Non-Repetitive Forward Surge Current

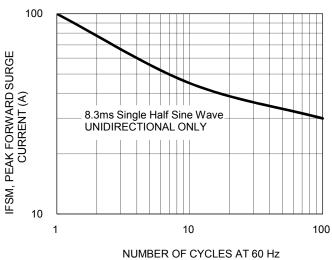
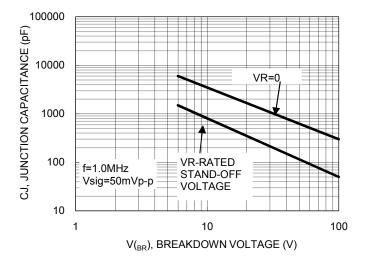




Fig5. Typical Junction Capacitance

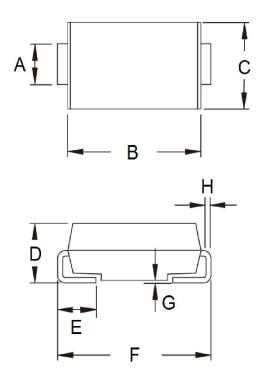






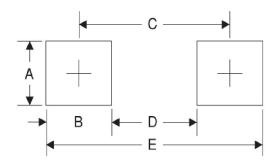
# **PACKAGE OUTLINE DIMENSIONS**

DO-214AA (SMB)



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	1.95	2.20	0.077	0.087	
В	4.05	4.60	0.159	0.181	
С	3.30	3.95	0.130	0.156	
D	1.95	2.65	0.077	0.104	
E	0.75	1.60	0.030	0.063	
F	5.10	5.60	0.201	0.220	
G	0.05	0.20	0.002	0.008	
Н	0.15	0.31	0.006	0.012	

## **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
A	2.3	0.091
В	2.5	0.098
С	4.3	0.169
D	1.8	0.071
E	6.8	0.268

## **MARKING DIAGRAM**



P/N = Marking Code
G = Green Compound
YW = Date Code
F = Factory Code



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